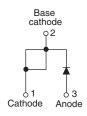


# Hyperfast Rectifier, 15 A Fred Pt®





| PRODUCT SUMMARY                  |            |  |  |  |  |
|----------------------------------|------------|--|--|--|--|
| Package                          | TO-220AC   |  |  |  |  |
| I <sub>F(AV)</sub>               | 15 A       |  |  |  |  |
| $V_{R}$                          | 600 V      |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 1.3 V      |  |  |  |  |
| t <sub>rr</sub> typ.             | 22 ns      |  |  |  |  |
| T <sub>J</sub> max.              | 175 °C     |  |  |  |  |
| Diode variation                  | Single die |  |  |  |  |

#### **FEATURES**

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Single die center tap module
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test



 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS                    |                                   |                         |             |       |  |  |  |
|---|-----------------------------------|-------------------------|-------------|-------|--|--|--|
| PARAMETER                                   | SYMBOL                            | TEST CONDITIONS         | VALUES      | UNITS |  |  |  |
| Peak repetitive reverse voltage             | V <sub>RRM</sub>                  |                         | 600         | V     |  |  |  |
| Average rectified forward current           | I <sub>F(AV)</sub>                | T <sub>C</sub> = 137 °C | 15          |       |  |  |  |
| Non-repetitive peak surge current           | I <sub>FSM</sub>                  | T <sub>J</sub> = 25 °C  | 120         | Α     |  |  |  |
| Peak repetitive forward current             | I <sub>FM</sub>                   |                         | 30          |       |  |  |  |
| Operating junction and storage temperatures | T <sub>J</sub> , T <sub>Stg</sub> |                         | -65 to +175 | °C    |  |  |  |

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                 |  |     |     |     |       |  |  |
|--|-----------------|--|-----|-----|-----|-------|--|--|
| PARAMETER  | SYMBOL          | TEST CONDITIONS MIN. TYP.                                      |     |     |     | UNITS |  |  |
| Breakdown voltage, blocking voltage  | $V_{BR}, V_{R}$ | $I_{R} = 100 \mu A$  | 600 | -   | -   |       |  |  |
| Forward voltage  | V <sub>F</sub>  | I <sub>F</sub> = 15 A  | -   | 1.8 | 2.2 | V     |  |  |
|  |                 | I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C                 | -   | 1.3 | 1.6 |       |  |  |
| Develop legisers assument  | I <sub>R</sub>  | V <sub>R</sub> = V <sub>R</sub> rated                          | -   | 0.2 | 50  |       |  |  |
| Reverse leakage current  |                 | T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated | -   | 30  | 500 | - μΑ  |  |  |
| Junction capacitance   | C <sub>T</sub>  | V <sub>R</sub> = 600 V   | -   | 20  | -   | pF    |  |  |
| Series inductance  | L <sub>S</sub>  | Measured lead to lead 5 mm from package body                   | -   | 8.0 | -   | nH    |  |  |



| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise specified) |                  |  |  |      |      |       |       |  |
|---|------------------|--|--|------|------|-------|-------|--|
| PARAMETER   | SYMBOL           | TEST CO  | MIN.   | TYP. | MAX. | UNITS |       |  |
|   |                  | $I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ |  | -    | 22   | -     |       |  |
| Reverse recovery time   |                  | $I_F = 15 \text{ A}, dI_F/dt = 100$  | $0 \text{ A/}\mu\text{s}, V_{\text{R}} = 30 \text{ V}$                                 | -    | 28   | -     | ns    |  |
| heverse recovery time   | t <sub>rr</sub>  | T <sub>J</sub> = 25 °C   |  | -    | 29   | -     |       |  |
|   |                  | T <sub>J</sub> = 125 °C  | $I_F = 15 \text{ A}$<br>$dI_F/dt = 200 \text{ A/}\mu\text{s}$<br>$V_R = 390 \text{ V}$ | -    | 75   | -     |       |  |
| Peak recovery current   | I <sub>RRM</sub> | T <sub>J</sub> = 25 °C   |  | -    | 3.5  | -     | А     |  |
| reak recovery current   |                  | T <sub>J</sub> = 125 °C  |  | -    | 7    | -     |       |  |
| Davage gasayan ahara  | 0                | T <sub>J</sub> = 25 °C   |  | -    | 57   | -     | nC    |  |
| Reverse recovery charge   | $Q_{rr}$         | T <sub>J</sub> = 125 °C  |  | -    | 300  | -     | nc nc |  |
| Reverse recovery time   | t <sub>rr</sub>  |  | I <sub>F</sub> = 15 A  | -    | 51   | -     | ns    |  |
| Peak recovery current   | I <sub>RRM</sub> | T <sub>J</sub> = 125 °C  | $dI_F/dt = 800 A/\mu s$  | -    | 20   | -     | А     |  |
| Reverse recovery charge   | Q <sub>rr</sub>  |  | V <sub>R</sub> = 390 V   | -    | 580  | -     | nC    |  |

| THERMAL MECHANICAL SPECIFICATIONS               |                                   |  |              |      |            |                        |  |  |
|---|-----------------------------------|--|--------------|------|------------|------------------------|--|--|
| PARAMETER                                       | SYMBOL                            | SYMBOL TEST CONDITIONS                     |              | TYP. | MAX.       | UNITS                  |  |  |
| Maximum junction and storage temperature range  | T <sub>J</sub> , T <sub>Stg</sub> |  | -65          | -    | 175        | °C                     |  |  |
| Thermal resistance, junction to case            | R <sub>thJC</sub>                 |  | -            | 1.1  | 1.4        |                        |  |  |
| Thermal resistance, junction to ambient per leg | R <sub>thJA</sub>                 | Typical socket mount                       | -            | -    | 70         | °C/W                   |  |  |
| Thermal resistance, case to heatsink            | R <sub>thCS</sub>                 | Mounting surface, flat, smooth and greased | -            | 0.5  | -          |                        |  |  |
| Weight  |                                   |  | -            | 2.0  | -          | g                      |  |  |
| Weight  |                                   |  | -            | 0.07 | -          | OZ.                    |  |  |
| Mounting torque                                 |                                   |  | 6.0<br>(5.0) | -    | 12<br>(10) | kgf · cm<br>(lbf · in) |  |  |
| Marking device                                  |                                   | Case style TO-220AC                        | 15ETH06H     |      |            |                        |  |  |

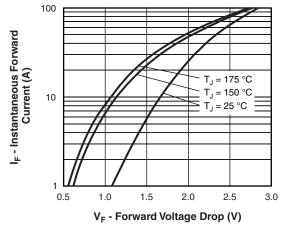


Fig. 1 - Typical Forward Voltage Drop Characteristics

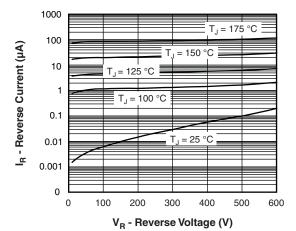


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

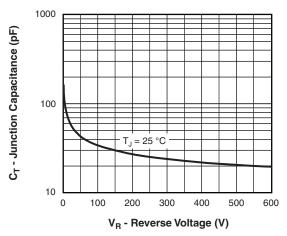


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

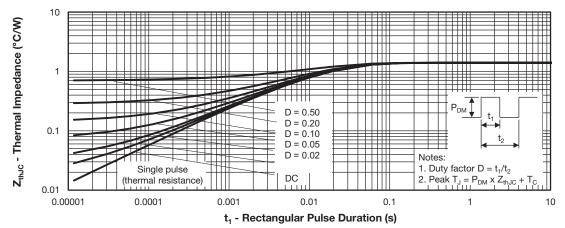


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

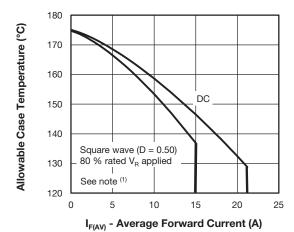


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

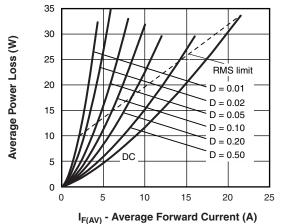


Fig. 6 - Forward Power Loss Characteristics

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# Vishay Semiconductors

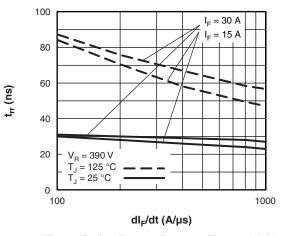


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

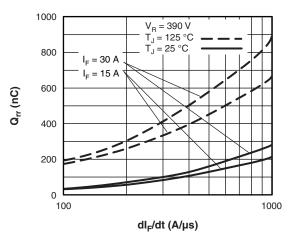
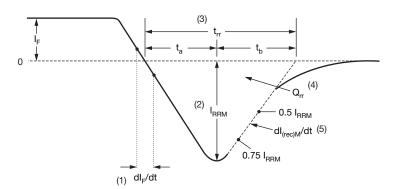


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times R_{\text{thJC}}; \\ \text{Pd} = \text{Forward power loss} = I_{\text{F(AV)}} \times V_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 8)}; \\ \text{Pd}_{\text{REV}} = \text{Inverse power loss} = V_{\text{R1}} \times I_{\text{R}} (1 - D); I_{\text{R}} \text{ at } V_{\text{R1}} = \text{Rated } V_{\text{R}} \\ \end{array}$ 



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_{rr}$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

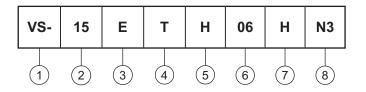
(5) dl<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions



#### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

Current rating (15 = 15 A)

3 - E = single diode

**4** -  $T = TO-220, D^2PAK$ 

H = hyperfast recovery

6 - Voltage rating (06 = 600 V)

7 - H = AEC-Q101 qualified

8 - Environmental digit:

N3 = halogen-free, RoHS compliant, and totally lead (Pb)-free

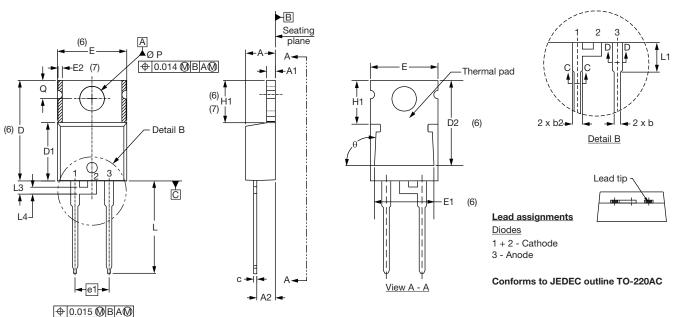
| ORDERING INFO | RMATION (Example) |                        |                         |
|---------------|-------------------|------------------------|-------------------------|
| PREFERRED P/N | QUANTITY PER T/R  | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION   |
| VS-15ETH06HN3 | 50                | 1000                   | Antistatic plastic tube |

| LINKS TO RELATED DOCUMENTS |             |                          |  |  |  |
|----------------------------|-------------|--------------------------|--|--|--|
| Dimensions                 | TO-220AC    | www.vishay.com/doc?95221 |  |  |  |
| Part marking information   | TO-220ACHN3 | www.vishay.com/doc?95068 |  |  |  |



### **TO-220AC**

#### **DIMENSIONS** in millimeters and inches



| SYMBOL   | MILLIM | IETERS | INCHES |       | NOTES |
|----------|--------|--------|--------|-------|-------|
| STINIBUL | MIN.   | MAX.   | MIN.   | MAX.  | NOTES |
| Α        | 4.25   | 4.65   | 0.167  | 0.183 |       |
| A1       | 1.14   | 1.40   | 0.045  | 0.055 |       |
| A2       | 2.56   | 2.92   | 0.101  | 0.115 |       |
| b        | 0.69   | 1.01   | 0.027  | 0.040 |       |
| b1       | 0.38   | 0.97   | 0.015  | 0.038 | 4     |
| b2       | 1.20   | 1.73   | 0.047  | 0.068 |       |
| b3       | 1.14   | 1.73   | 0.045  | 0.068 | 4     |
| С        | 0.36   | 0.61   | 0.014  | 0.024 |       |
| c1       | 0.36   | 0.56   | 0.014  | 0.022 | 4     |
| D        | 14.85  | 15.25  | 0.585  | 0.600 | 3     |
| D1       | 8.38   | 9.02   | 0.330  | 0.355 |       |
| D2       | 11.68  | 12.88  | 0.460  | 0.507 | 6     |
| Е        | 10.11  | 10.51  | 0.398  | 0.414 | 3, 6  |

| SYMBOL   | MILLIM | IETERS | INCHES     |       | NOTES |
|----------|--------|--------|------------|-------|-------|
| STINIBUL | MIN.   | MAX.   | MIN.       | MAX.  | NOTES |
| E1       | 6.86   | 8.89   | 0.270      | 0.350 | 6     |
| E2       | -      | 0.76   | -          | 0.030 | 7     |
| е        | 2.41   | 2.67   | 0.095      | 0.105 |       |
| e1       | 4.88   | 5.28   | 0.192      | 0.208 |       |
| H1       | 6.09   | 6.48   | 0.240      | 0.255 | 6, 7  |
| L        | 13.52  | 14.02  | 0.532      | 0.552 |       |
| L1       | 3.32   | 3.82   | 0.131      | 0.150 | 2     |
| L3       | 1.78   | 2.13   | 0.070      | 0.084 |       |
| L4       | 0.76   | 1.27   | 0.030      | 0.050 | 2     |
| ØΡ       | 3.54   | 3.73   | 0.139      | 0.147 |       |
| Q        | 2.60   | 3.00   | 0.102      | 0.118 |       |
| θ        | 90° t  | o 93°  | 90° to 93° |       |       |
|          |        |        |            |       |       |

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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